

## FAST RECOVERY RECTIFIER DIODES

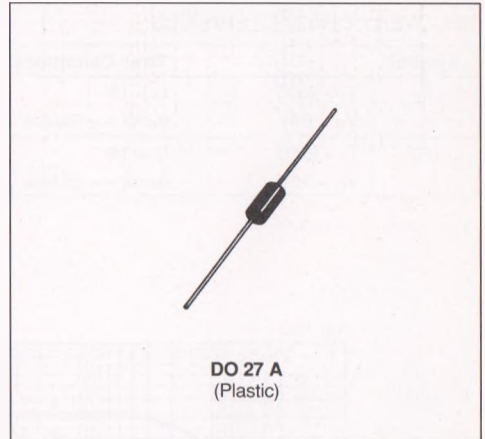
- LOW FORWARD VOLTAGE DROP
- HIGH SURGE CURRENT CAPABILITY

### APPLICATIONS

- AC-DC POWER SUPPLIES AND CONVERTERS
- FREE WHEELING DIODES, etc.

### DESCRIPTION

Their high efficiency and high reliability combined with small size and low cost make these fast recovery rectifier diodes very attractive components for many demanding applications.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{FRM}$	Repetitive Peak Forward Current	$t_p \leq 20\mu s$	100	A
$I_{F(AV)}$	Average Forward Current*	$T_a = 90^\circ C$	3	A
$I_{FSM}$	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	150	A
$P_{Tot}$	Power Dissipation*	$T_a = 90^\circ C$	3.5	W
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 40 to 175	$^\circ C$
$T_L$	Maximum Lead Temperature for Soldering during 10s at 4mm from Case		230	$^\circ C$

Symbol	Parameter	PFR					Unit
		850	851	852	854	856	
$V_{RRM}$	Repetitive Peak Reverse Voltage	50	100	200	400	600	V
$V_{RSM}$	Non Repetitive Peak Reverse Voltage	75	150	250	450	650	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction-ambient*	25	$^\circ C/W$

\* On infinite heatsink with 10mm lead length.

**ELECTRICAL CHARACTERISTICS**

**STATIC CHARACTERISTICS**

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$I_R$	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			10	$\mu\text{A}$
	$T_j = 100^\circ\text{C}$				500	
$V_F$	$T_j = 25^\circ\text{C}$	$I_F = 3\text{A}$			1.25	V

**RECOVERY CHARACTERISTICS**

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$t_{rr}$	$T_j = 25^\circ\text{C}$ $V_R = 30\text{V}$	$I_F = 1\text{A}$	PFR 850 → 854		150	ns
		$d_{iF}/dt = -25\text{A}/\mu\text{s}$			200	
$I_{RM}$	$T_j = 25^\circ\text{C}$ $V_R = 30\text{V}$	$I_F = 1\text{A}$ $d_{iF}/dt = -25\text{A}/\mu\text{s}$			2	A

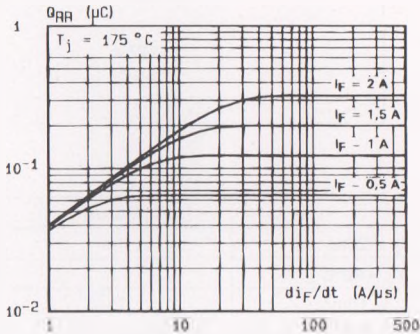
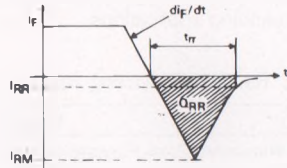


Fig.1 Recovered charge versus  $d_{iF}/dt$  (typical values).



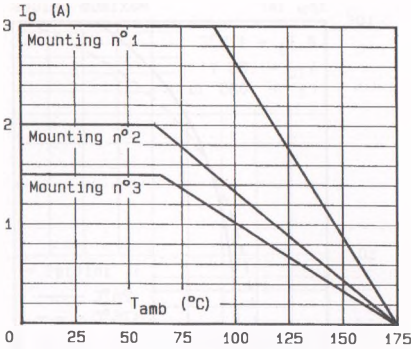


Fig.2 - Mean forward current  $I_D$  versus ambient temperature (maximum values).

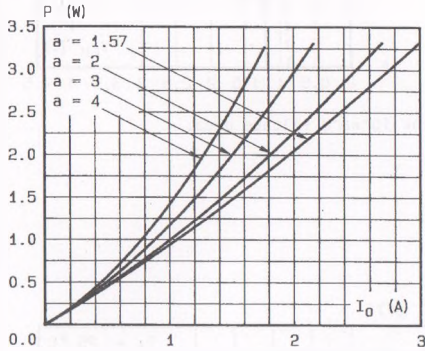


Fig.4 - Mean power dissipation versus mean forward current  $I$  for different rectifying types, in the case of :  
 - a resistive load ( $a = 1.57$ )  
 - a capacitive load ( $a > 1.57$ )

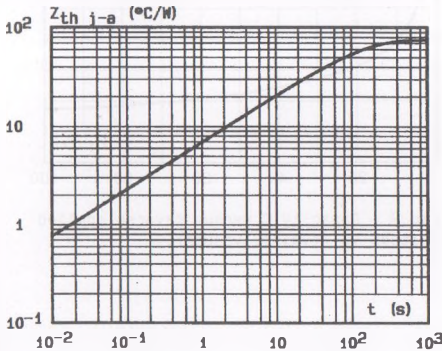


Fig.5 - Transient thermal impedance junction-ambient for mounting n°2 versus pulse duration ( $L = 10$  mm)

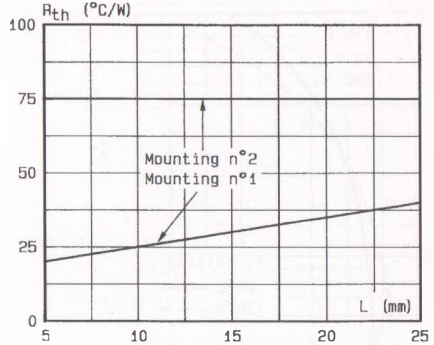
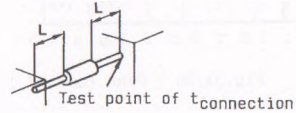
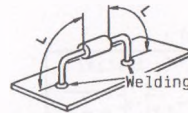


Fig.3 - Thermal resistance versus lead length (maximum values).

Mounting n°1 : INFINITE HEATSINK



Mounting n°2 : PRINTED CIRCUIT



Mounting n°3 :  
 $L = 10$  mm  
 $R_{th} = 55$  °C/W

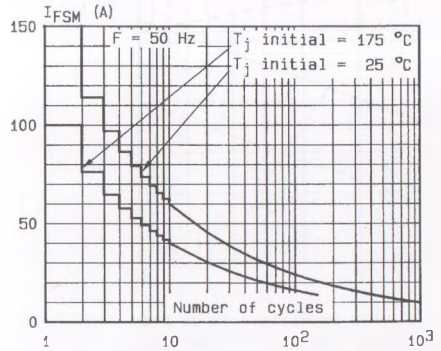
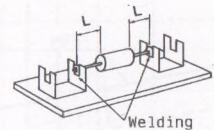


Fig.6 - Non repetitive surge peak forward current versus number of cycles.

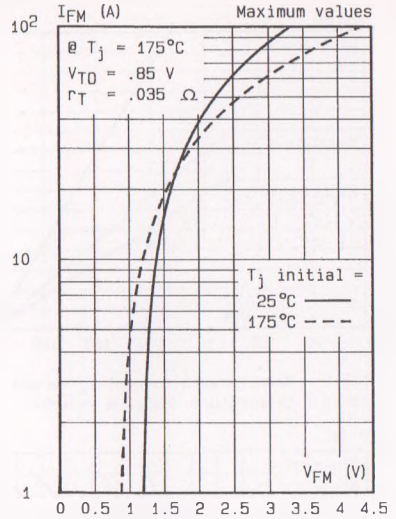
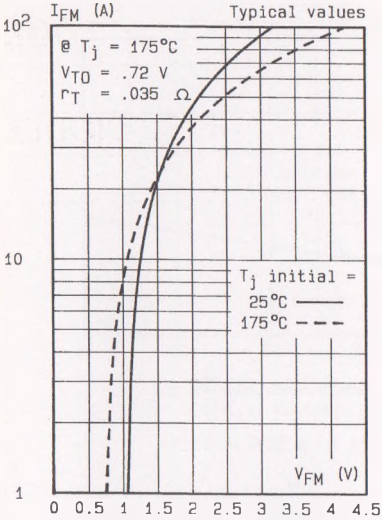


Fig.3a/3b - Peak forward current versus peak forward voltage drop.

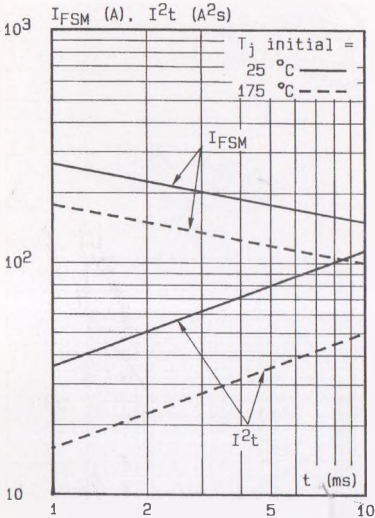


Fig.8 - Non repetitive surge peak forward current for a sinusoidal pulse with width :  $t \leq 10\text{ ms}$ , and corresponding value of  $I^2t$ .

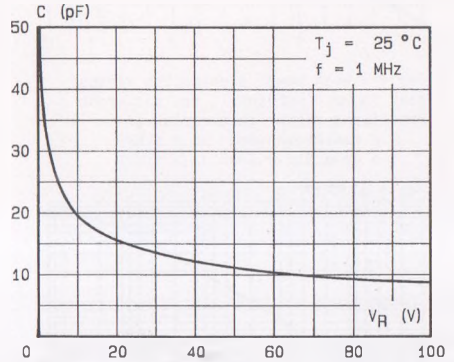


Fig.9 - Capacity  $C$  versus reverse applied voltage  $V_R$  (typical values).